Docket No.: 071971-0015

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PATENT



IN THE UNITED STATES **PATENT AND TRADEMARK OFFICE**

In re Application of

Customer Number: 20277

Shiro SAKIYAMA, et al.

Confirmation Number: CNF NO. 6689

Application No.: 10/511,165

Group Art Unit: 2816

Filed: October 14, 2004

Examiner: HILTUNEN, THOMAS J

For: SEMICONDUCTOR INTEGRATED CIRCUIT

SECOND REQUEST FOR CORRECTED FILING RECEIPT

Mail Stop OFR Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Attached is a copy of the Filing Receipt received from the U.S. Patent and Trademark Office in the above-referenced application. It is noted that the Domestic priority data is incorrect. Attached is a copy of the Front Page of the Published International Application, which evidences that the Domestic Priority data should read: PCT/JP04/01942 02/19/2004. It is requested that a corrected filing receipt be issued.

Respectfully submitted,

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CONFIRMATION NO. 6689

20277
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FILING RECEIPT

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Date Mailed: 04/08/2005

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

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Power of Attorney: The patent practitioners associated with Customer Number 20277.

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This application is a 371 of PCT/JP04/01942 02/19/20\$\psi 3

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Title

Semiconductor integrated circuit

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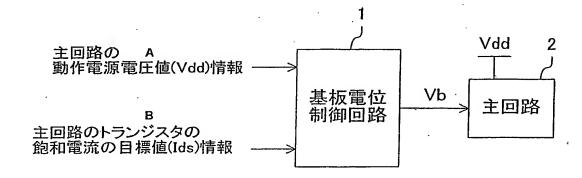
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- (54) Title: SEMICONDUCTOR INTEGRATED CIRCUIT
- (54) 発明の名称: 半導体集積回路



A...INFORMATION CONCERNING OPERATING POWER SUPPLY VOLTAGE (Vdd) OF MAIN CIRCUIT
B...INFORMATION CONCERNING TARGET SATURATION
CURRENT VALUE (Ids) OF TRANSISTOR OF MAIN CIRCUIT
1...SUBSTRATE POTENTIAL CONTROLLING CIRCUIT
2...MAIN CIRCUIT

(57) Abstract: A semiconductor integrated circuit comprises a main circuit (2) which is composed of a MOS transistor wherein a source and a substrate are separated from each other. A substrate potential controlling circuit (1) controls the substrate potential of the MOS transistor of the main circuit (2) so that the actual saturation current value of the MOS transistor which constitutes the main circuit (2) becomes equal to a target saturation current value (Ids) of the main circuit (2) at the operating power supply voltage (Vdd). Consequently, even when the operating power supply voltage of the semiconductor integrated circuit is lowered, variations in the operating speed can be suppressed within a small range.

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